

Supporting Information

Dynamic Ferroelectric Transistor-based Reservoir Computing for Spatiotemporal Information Processing

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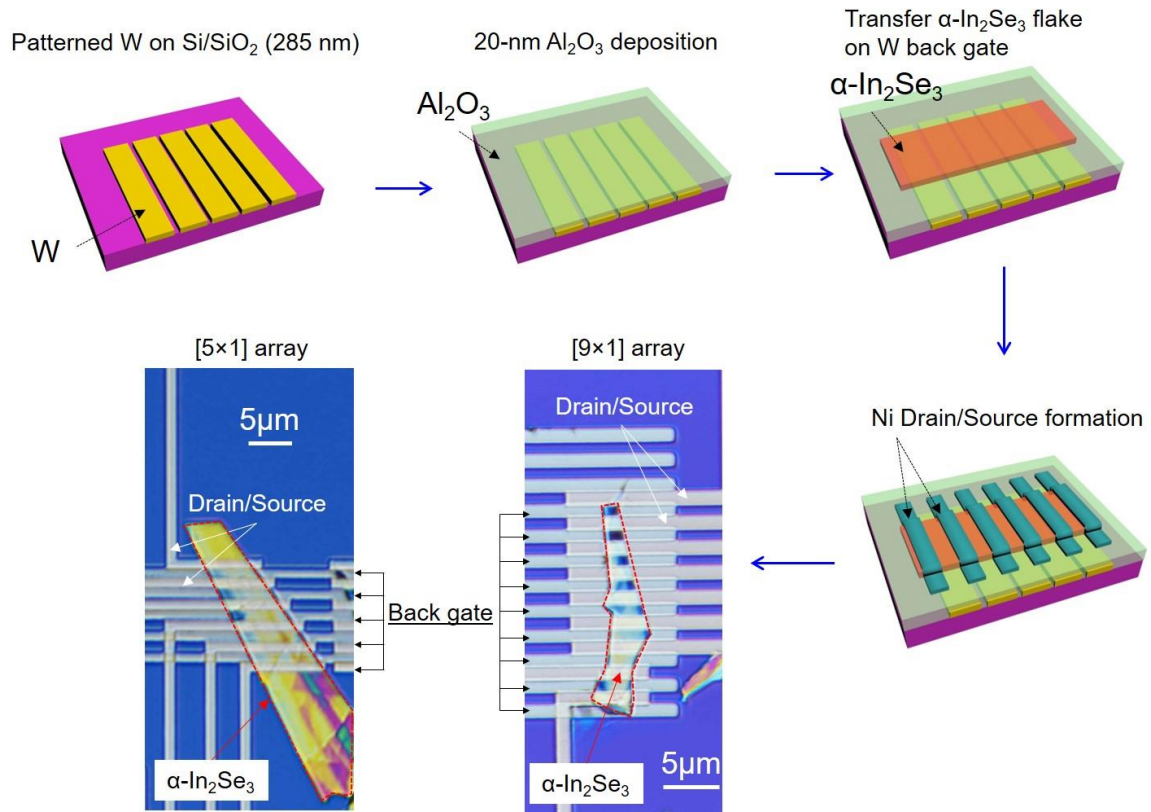


Figure S1. 1D array fabrication techniques and optical images of [5×1] and [9×1] array.

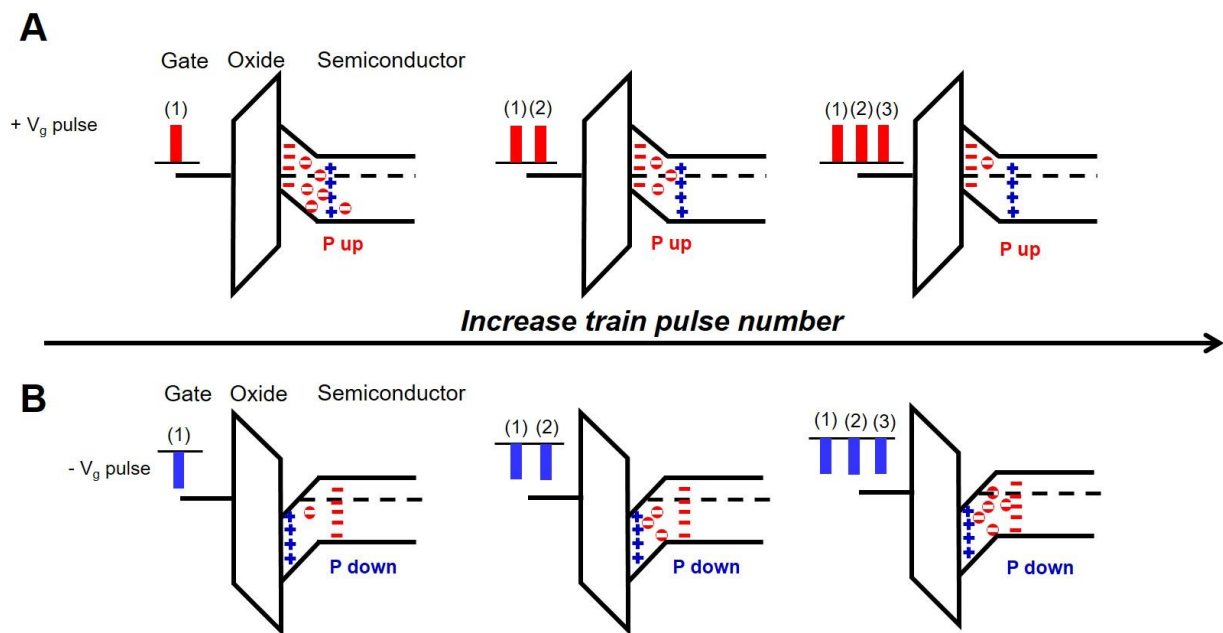


Figure S2. Band alignment showing charge distribution at two polarization direction in α -In₂Se₃ which explain for the change in channel conductance after applying series discrete (a) positive and (b) negative V_g pulses.

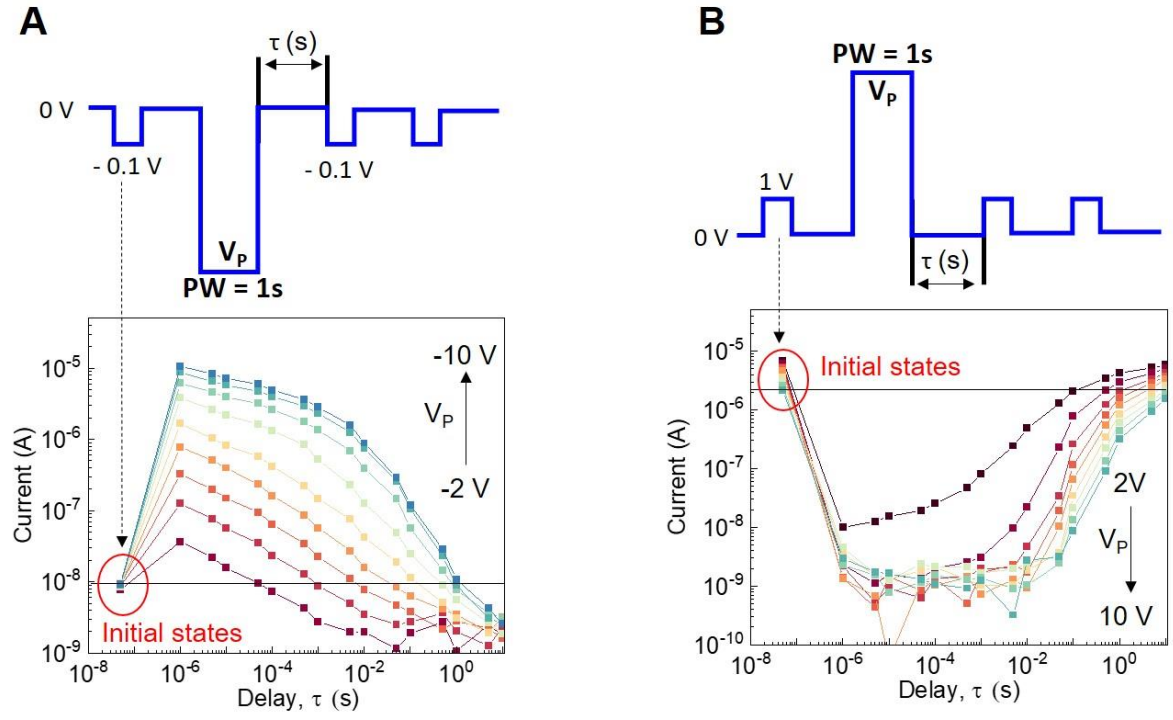


Figure S3. Drain currents read at various delay time τ (s) after writing by (A) negative and erasing by (B) positive V_p . In both regimes, the conductances retrieved their initial states after a very short time delay (< 1 s).

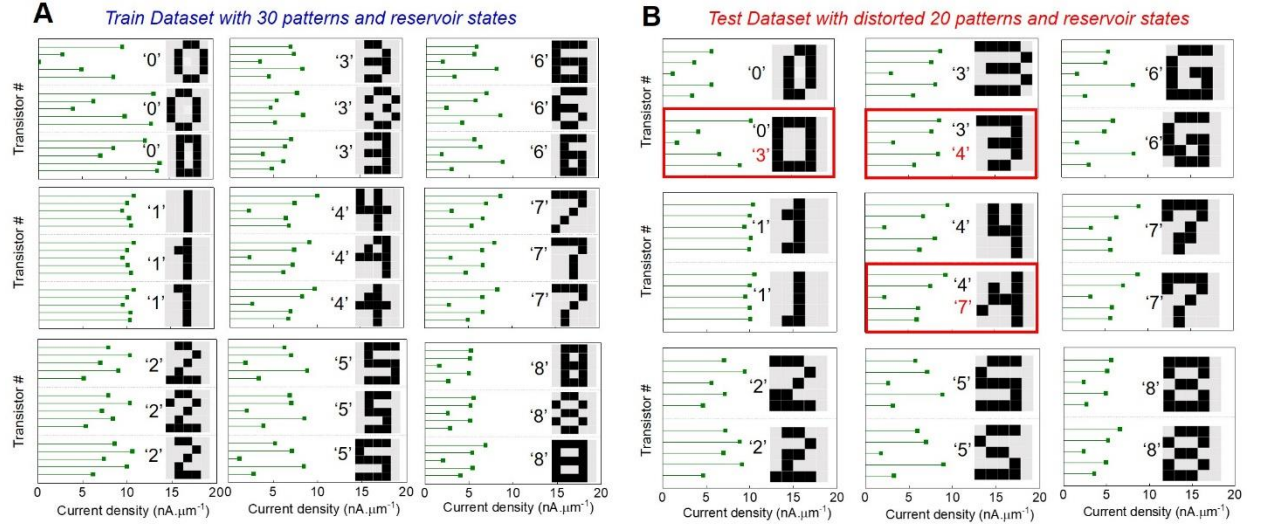


Figure S4. Dataset for pattern recognition (a) 30 images training dataset showing different digits with corresponding reservoir states experimentally measured by [5×1] transistor array. (b) 20 distorted images for testing with purposely created noises by adding or deleting random fixels. Red-marked three wrongly predicted digit '0', '3', and '4'.

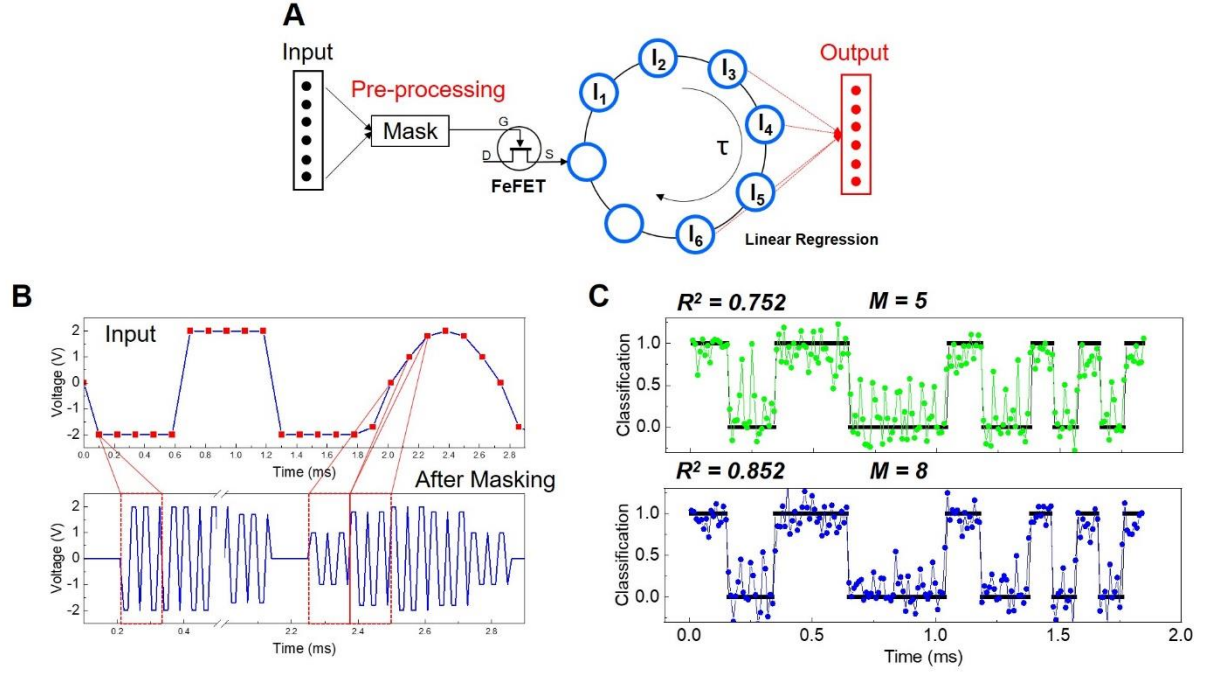


Figure S5. Waveform classification task. (a) Concept of cyclic reservoir in which input data is time-multiplexed by a masking process to create the sequential input voltages. Next, the input voltages stream in (b) is then applied to our α - In_2Se_3 FeS-FET to record to virtual nodes in reservoir space. The virtual nodes are connected to each other by a time sequence. The number of virtual nodes are decided by the mask length, M . The virtual node are then sent to readout layer with simple linear regression. (c) The classification results and R^2 with increasing mask length, $M = 5$ and 8 .

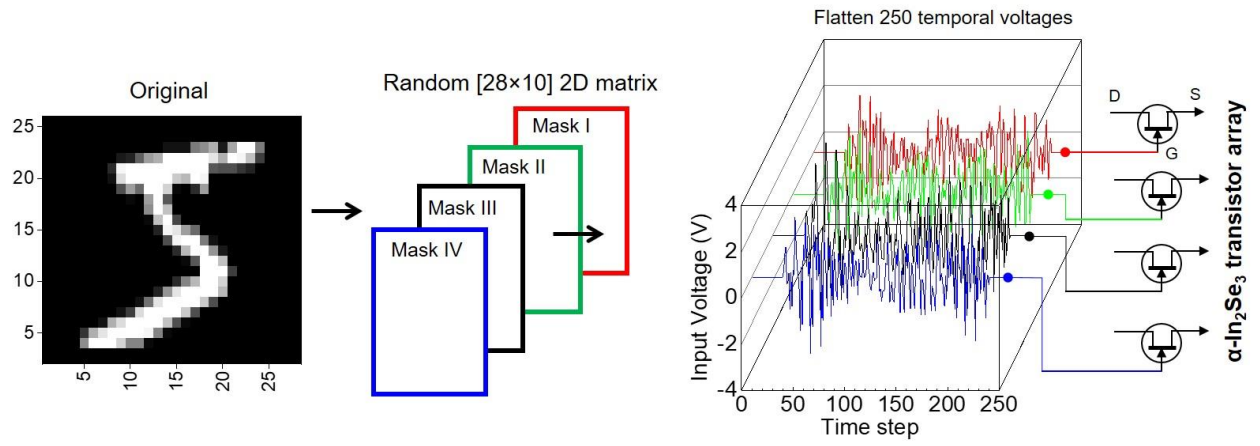


Figure S6. Image in MNIST database is pre-processed by multiplying with 2D mask $[28 \times 10]$ to generated temporal input voltage, $V(t)$ with time delay $\tau = 120 \mu\text{s}$. The $V(t)$ is then streamed through a 1D array of devices to sense conductance states (virtual nodes) for further training and testing.

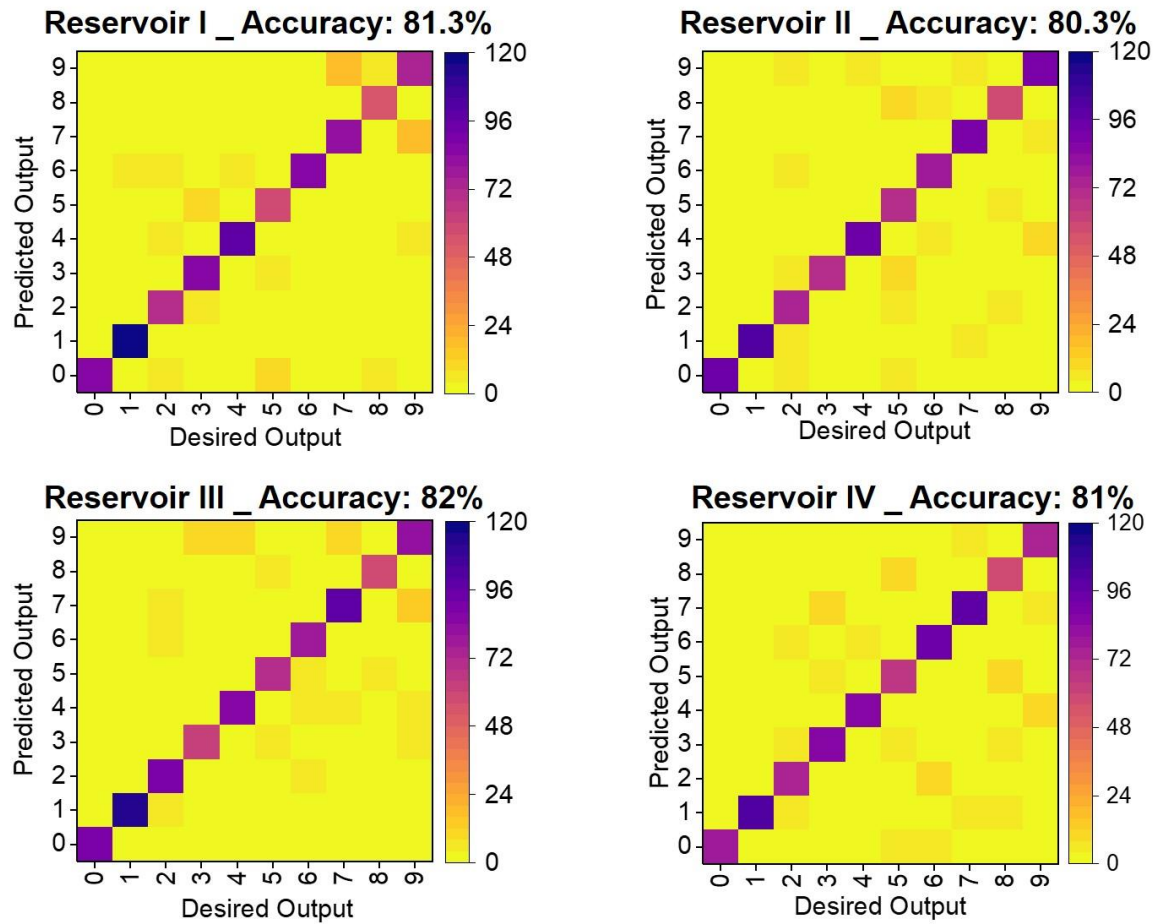


Figure S7. Detail confusion matrices for 4 different reservoirs as shown in Fig. 4 B

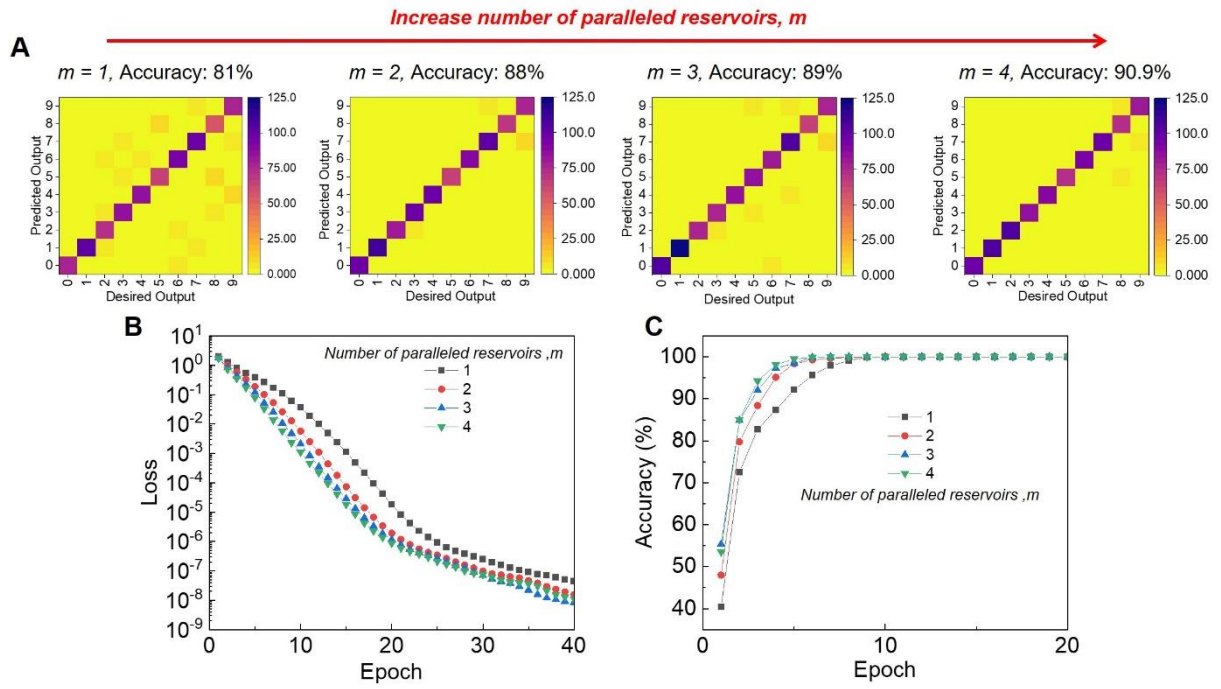


Figure S8. (a) Confusion matrices of testing, (b) Loss and (c) Accuracy versus training epoch process with increasing number of paralleled reservoirs, m

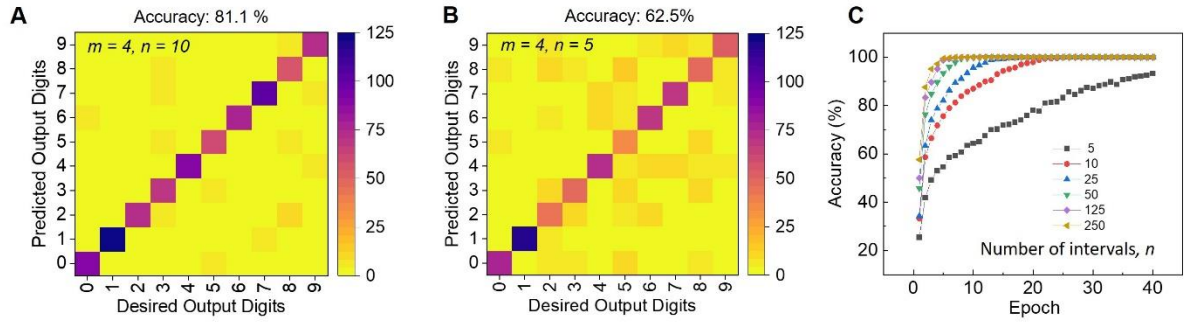


Figure S9. Confusion matrices at with 4 paralleled reservoirs, $m = 4$ at different input selection intervals: (a) $n = 10$ and (b) $n = 5$ showing accuracy = 81.1 % and 62.5 %, respectively. (c) Accuracy *versus* 40 training epoch with increase number of selected virtual nodes, n

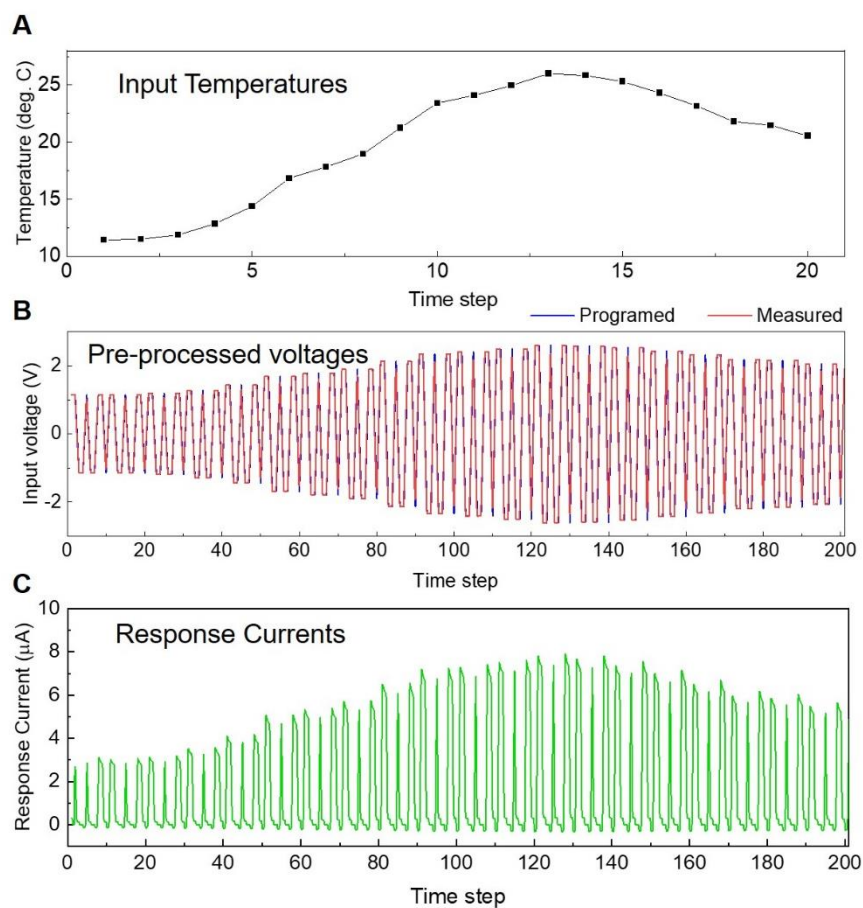


Figure S10. (a) Time-series daily temperature serves as input layer in RC systems. (b) Programmed and measured time-multiplexed input voltages after masking the input temperature in figure S10 a. (c) Response currents of FeS-FET utilized as virtual nodes for readout function.

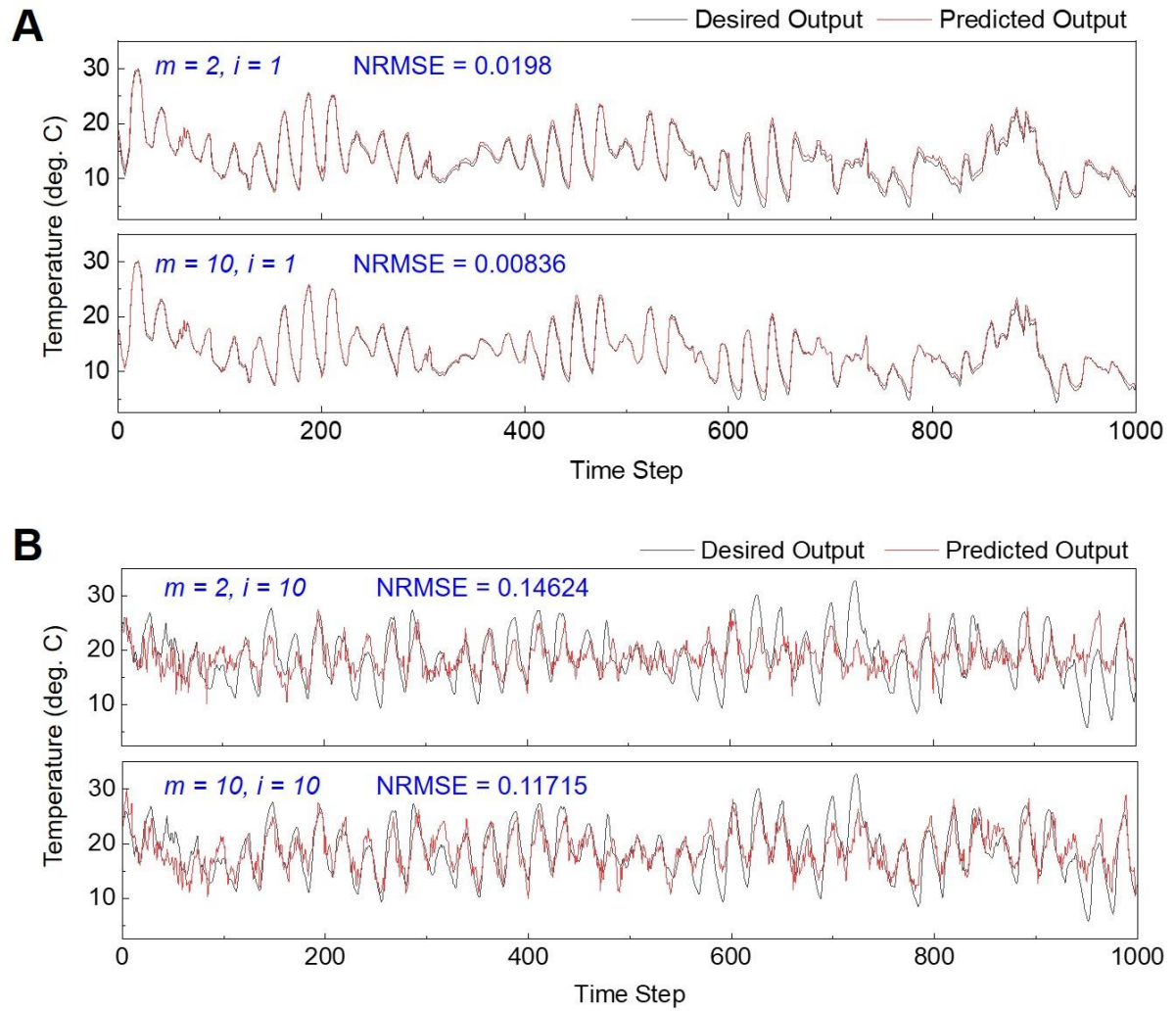


Figure S11. Visualization of predicted and desired output for 1000 testing dataset and their compromised NRMSE at some steps prediction ahead, i : (a) $i = 1$ and (b) $i = 10$ with $m = 2$ and 10 .

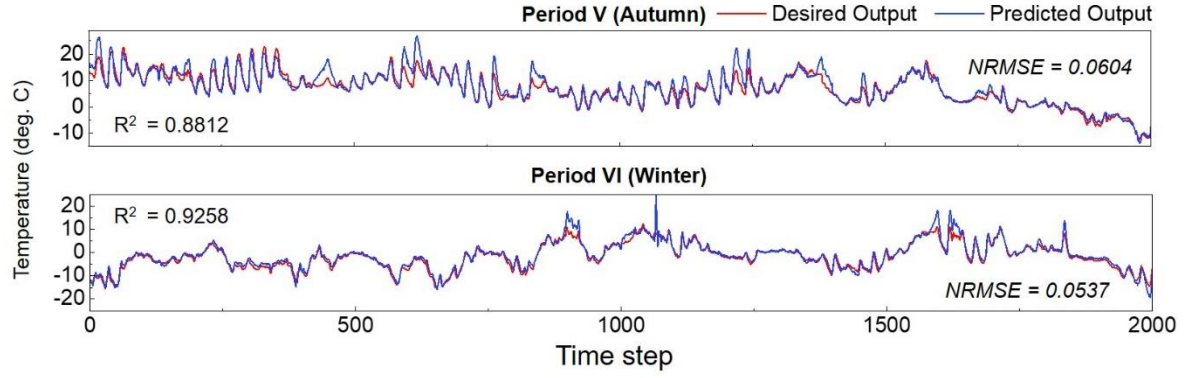


Figure S12. Desired and predicted output for testing period V (Autumn) and VI (Winter) and its corresponding R^2 and NRMSE.

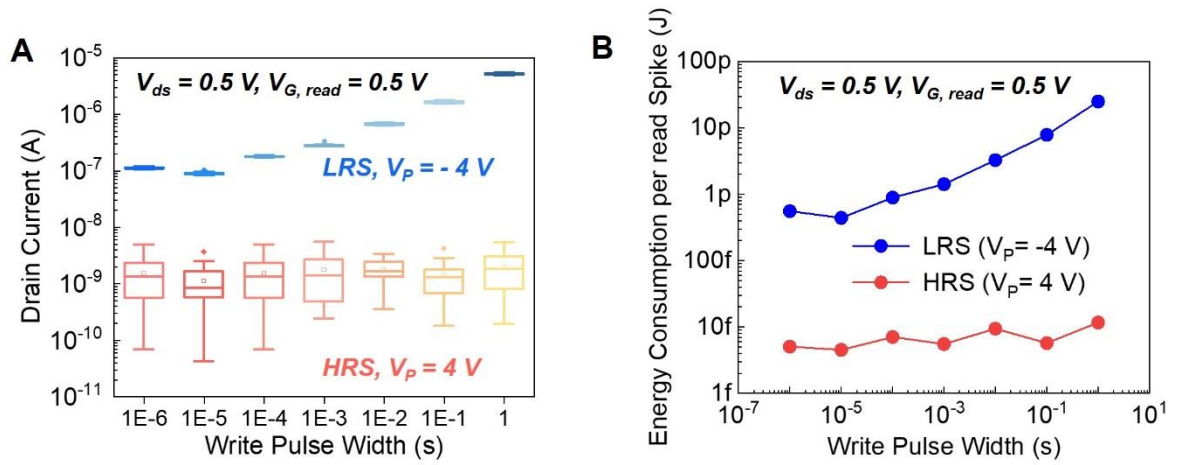


Figure S13. (a) Resistive switching with different writing speeds. LRS/HRS ratio increases with the increase of writing widths. (b) Power consumption within a reading spike (0.5 V, 20 μ s) of our fading Ferro RC versus writing speed.